

Standard Recovery Diodes, (Stud Version), 400 A



DO-9 (DO-205AB)

FEATURES

- Wide current range
- High voltage ratings up to 2400 V
- High surge current capabilities
- Stud cathode and stud anode version
- Standard JEDEC® types
- Compression bonded encapsulations
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912


**RoHS
COMPLIANT**

PRIMARY CHARACTERISTICS

$I_{F(AV)}$	400 A
Package	DO-9 (DO-205AB)
Circuit configuration	Single

TYPICAL APPLICATIONS

- Converters
- Power supplies
- Machine tool controls
- High power drives
- Medium traction applications

MAJOR RATINGS AND CHARACTERISTICS

PARAMETER	TEST CONDITIONS	VALUES	UNITS
$I_{F(AV)}$		480	A
	T_C	120	°C
$I_{F(RMS)}$		630	A
I_{FSM}	50 Hz	8250	
	60 Hz	8640	
I^2t	50 Hz	340	kA ² s
	60 Hz	311	
V_{RRM}	Range	1600 to 2400	V
T_J		-40 to +190	°C

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS

TYPE NUMBER	VOLTAGE CODE	V_{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V_{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I_{RRM} MAXIMUM AT $T_J = T_J$ MAXIMUM mA
VS-SD400N/R	16	1600	1700	15
	20	2000	2100	
	24	2400	2500	



FORWARD CONDUCTION					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current at case temperature	$I_{F(AV)}$	180° conduction, half sine wave		400	A
				120	°C
				480	A
				100	°C
Maximum RMS forward current	$I_{F(RMS)}$	DC at 110 °C case temperature		630	A
Maximum peak, one-cycle forward, non-repetitive surge current	I_{FSM}	t = 10 ms	No voltage reappplied	8250	
		t = 8.3 ms	No voltage reappplied	8640	
		t = 10 ms	100 % V_{RRM} reappplied	6940	
		t = 8.3 ms	100 % V_{RRM} reappplied	7270	
Maximum I^2t for fusing	I^2t	t = 10 ms	No voltage reappplied	340	kA ² s
		t = 8.3 ms	No voltage reappplied	311	
		t = 10 ms	100 % V_{RRM} reappplied	241	
		t = 8.3 ms	100 % V_{RRM} reappplied	220	
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	t = 0.1 to 10 ms, no voltage reappplied		3400	kA ² √s
Low level value of threshold voltage	$V_{F(TO)1}$	$(16.7 \% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$, $T_J = T_J$ maximum		0.80	V
High level value of threshold voltage	$V_{F(TO)2}$	$(I > \pi \times I_{F(AV)})$, $T_J = T_J$ maximum		0.85	
Low level value of forward slope resistance	r_{f1}	$(16.7 \% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$, $T_J = T_J$ maximum		0.55	mW
High level value of forward slope resistance	r_{f2}	$(I > \pi \times I_{F(AV)})$, $T_J = T_J$ maximum		0.51	
Maximum forward voltage drop	V_{FM}	$I_{pk} = 1500$ A, $T_J = T_J$ maximum, $t_p = 10$ ms sinusoidal wave		1.62	V

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum junction operating temperature range	T_J			-40 to +190	°C
Maximum storage temperature range	T_{Stg}			-55 to +200	
Maximum thermal resistance, junction to case	R_{thJC}	DC operation		0.11	K/W
Maximum thermal resistance, case to heatsink	R_{thCS}	Mounting surface, smooth, flat and greased		0.04	
Maximum allowed mounting torque ± 10 %		Not-lubricated threads		27	Nm
Approximate weight				250	g
Case style		See dimensions (link at the end of datasheet)		DO-9 (DO-205AB)	

ΔR_{thJC} CONDUCTION				
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS
180°	0.020	0.013	$T_J = T_J$ maximum	K/W
120°	0.023	0.023		
90°	0.029	0.031		
60°	0.042	0.044		
30°	0.073	0.074		

Note

- The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

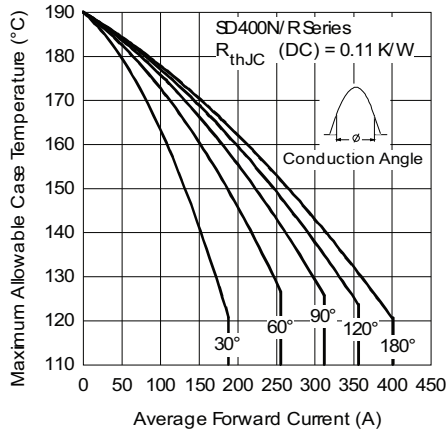


Fig. 1 - Current Ratings Characteristics

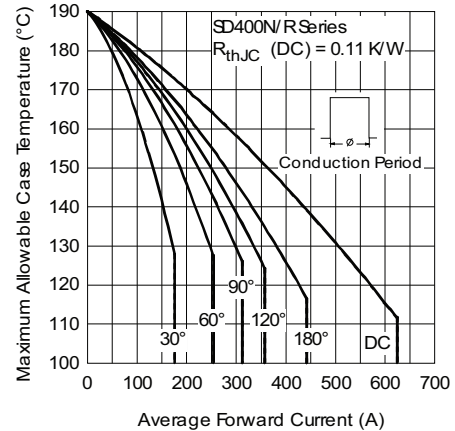


Fig. 2 - Current Ratings Characteristics

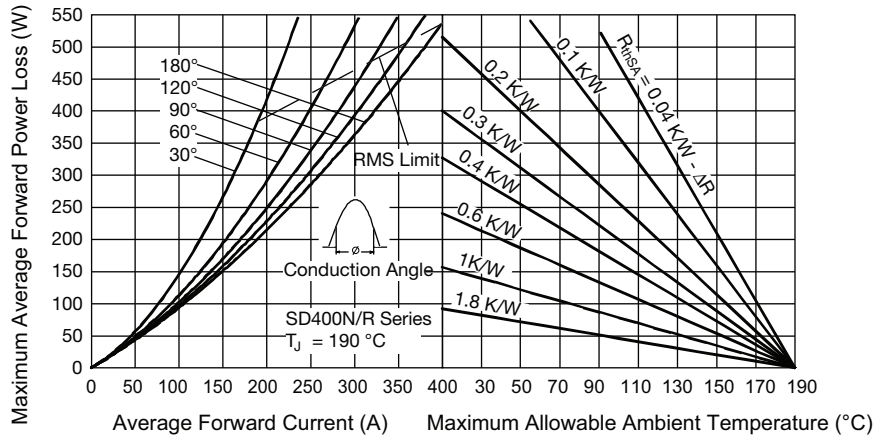


Fig. 3 - Forward Power Loss Characteristics

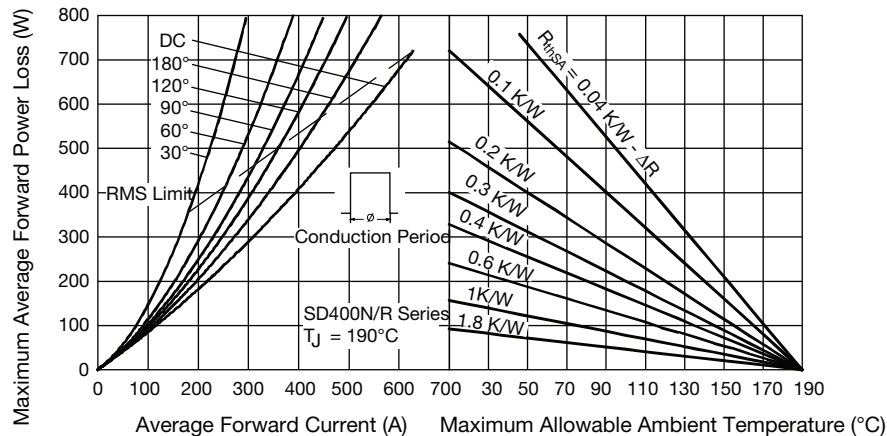


Fig. 4 - Forward Power Loss Characteristics

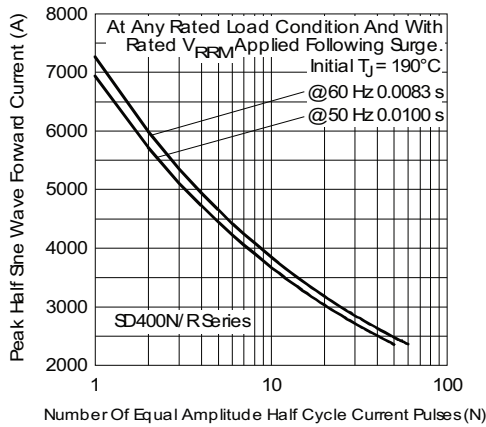


Fig. 5 - Maximum Non-Repetitive Surge Current

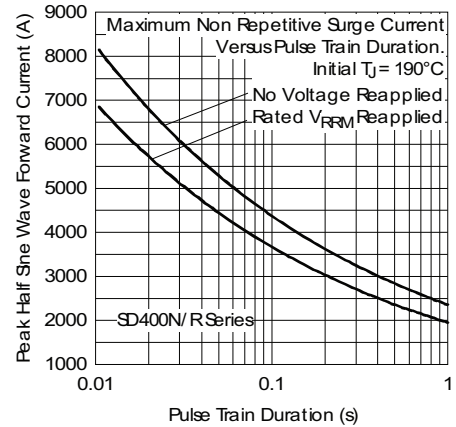


Fig. 6 - Maximum Non-Repetitive Surge Current

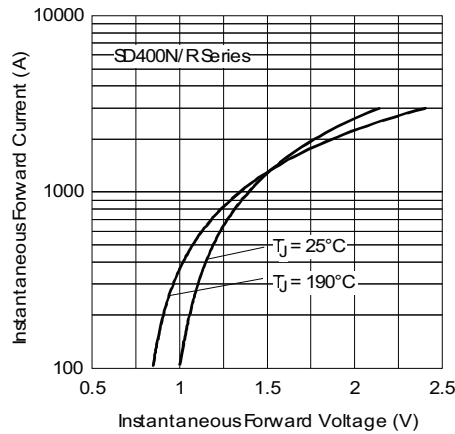


Fig. 7 - Forward Voltage Drop Characteristics

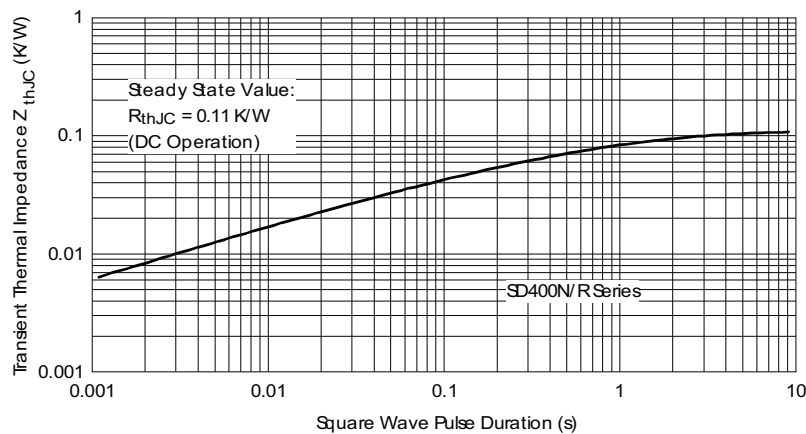
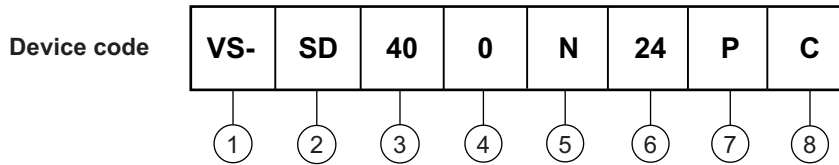


Fig. 8 - Thermal Impedance Z_{thJC} Characteristic



ORDERING INFORMATION TABLE

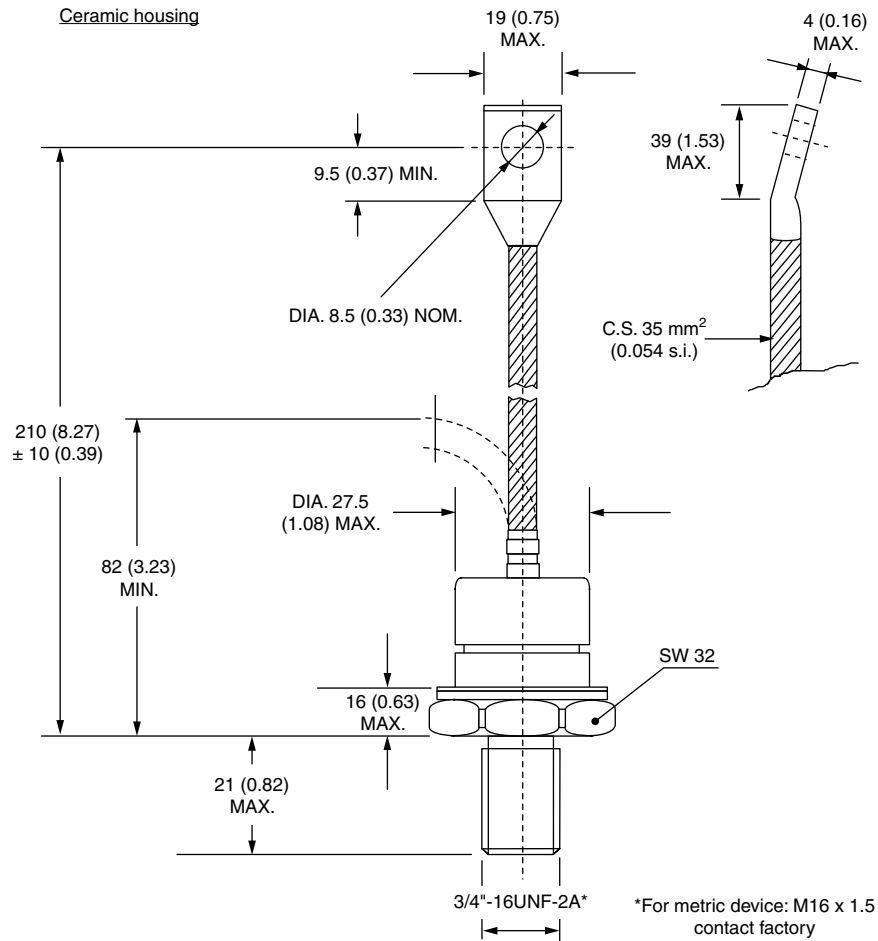


- 1** - Vishay Semiconductors product
- 2** - Diode
- 3** - Essential part number
- 4** - 0 = standard recovery
- 5** -
 - N = stud normal polarity (cathode to stud)
 - R = stud reverse polarity (anode to stud)
- 6** - Voltage code x 100 = V_{RRM} (see Voltage Ratings table)
- 7** - P = stud base DO-9 (DO-205AB) 3/4" 16UNF-2A
- 8** - C = ceramic housing

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95301

DO-205AB (DO-9)

DIMENSIONS in millimeters (inches)





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